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Dielectric Behavior near a Smectic A_d -Smectic A_2 Critical Point

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We present precise measurements of the static dielectric constant near the smectic A_d -smectic A_2 critical point in a binary system. Detailed analysis of the data obtained for several mixtures has been done to locate the critical point concentration. Results of a dielectric dispersion study near the A_d - A_2 transition are also presented.

Keywords: A-A transition, critical point, dielectric studies

INTRODUCTION

According to the mean-field theory,¹ the A_d - A_2 transition is identical to the liquid-gas transition and as such can terminate at a critical point. (Here A_d and A_2 refer to the partially bilayer and bilayer smectic A phases respectively.) More rigorous treatments of the transition have since been proposed.^{2,3}

The first experimental observation⁴ of the A_d - A_2 critical point was in a binary system of 4-*n*-undecyloxyphenyl-4'-(4''-cyanobenzyloxy) benzoate (or 110PCB0B) and 4-*n*-nonyloxybiphenyl-4'-cyano benzoate (or 90BCB), employing high precision x-ray techniques. Subsequently, high resolution calorimetric studies⁵ were conducted on the same system which confirmed the conclusions arrived at from the x-ray studies. In the present paper, we report precise dielectric measurements on the same binary system, which again reveal the critical point in a striking fashion. The results of these measurements are in excellent quantitative agreement with the x-ray and calorimetric experiments.

EXPERIMENTAL

The measurements were carried out using an impedance analyser (HP 4192A). The static dielectric constants (ϵ_{\parallel} and ϵ_{\perp}) were determined at 10 kHz. The low frequency ϵ_{\parallel} dispersion studies were done in the frequency range of 1 kHz–13 MHz. The sample (thickness $\sim 25 \mu\text{m}$) was aligned by cooling it from the nematic phase at a slow rate in the presence of a 2.4T magnetic field. The static measurements were carried out by varying the temperature at a uniform rate of 4–5°C/hour. During any dispersion measurements the temperature was maintained to a constancy of 25 mK. In all we have studied eight binary mixtures, $x = 0.55, 0.59, 0.63, 0.65, 0.68, 0.72, 0.80, 0.90$ in addition to the pure compound 110PCB0B. Here x indicates the mole fraction of 110PCB0B in the mixture.

RESULTS AND DISCUSSION

Figures 1 and 2 show the temperature variation of ϵ_{\parallel} and ϵ_{\perp} in the A_d and A_2 phases, for $x = 0.63$ and 0.80. Whereas, $x = 0.63$ shows a steep change in ϵ_{\parallel} and ϵ_{\perp} across the transition ($\sim 120.7^\circ\text{C}$), $x = 0.80$ shows a much smoother variation with change of temperature. Previous x-ray studies⁴ had identified $x = 0.642$ as the critical point concentration. Thus, $x = 0.63$ should show a first-order transition while $x = 0.80$ a continuous evolution without any phase transition. The clear difference between the curves for these two concentrations does indeed reflect this.

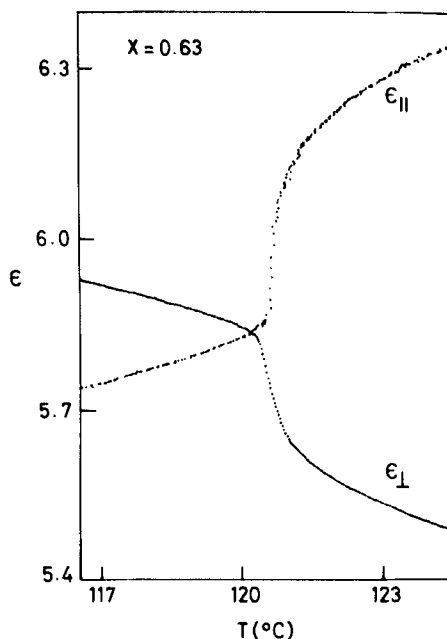


FIGURE 1 Temperature variation of ϵ_{\parallel} and ϵ_{\perp} for $x = 0.63$.

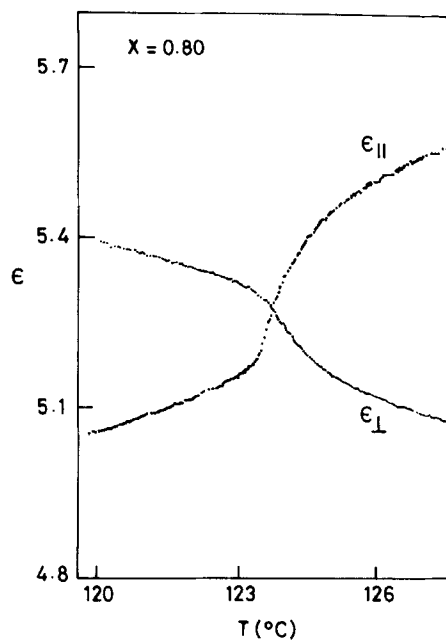


FIGURE 2 Plot of $\epsilon_{||}$ and ϵ_{\perp} as a function of temperature for $x = 0.80$.

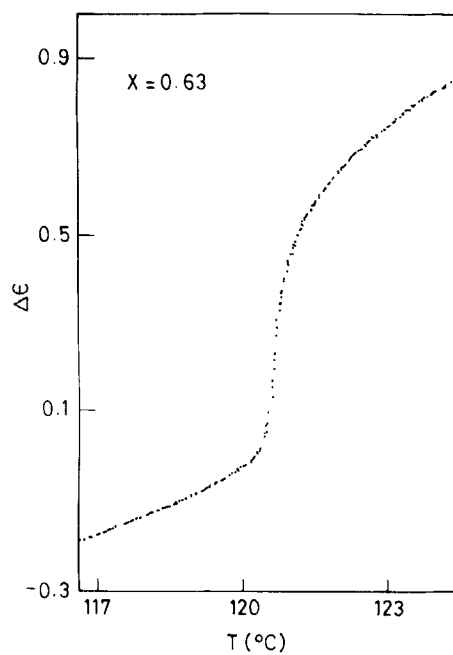
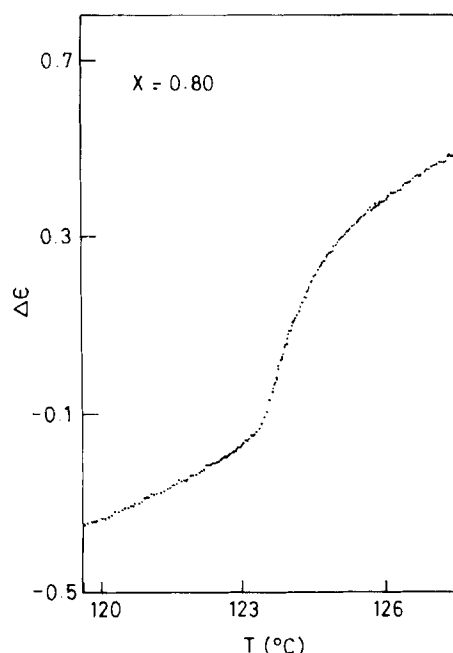


FIGURE 3 The variation of the dielectric anisotropy $\Delta\epsilon$ with temperature for $x = 0.63$.

FIGURE 4 $\Delta\epsilon$ versus temperature for $x = 0.80$.

As seen in Figures 1 and 2, there is a cross-over in the values of ϵ_{\parallel} and ϵ_{\perp} near the transition. This feature has been observed for all the concentrations studied, though the relative thermal variation of ϵ_{\parallel} and ϵ_{\perp} depends on the concentration. This effect is clearly shown up in the plots (Figures 3 and 4) of the dielectric anisotropy ($\Delta\epsilon = \epsilon_{\parallel} - \epsilon_{\perp}$) as a function of temperature. Although the steepness of the $\Delta\epsilon$ variation near the transition shows a concentration dependence, it was not significant enough to locate the critical point accurately.

In order to locate the critical point precisely we have proceeded as follows: The data of $\Delta\epsilon$ versus T has been fitted to an expression of the form

$$\Delta\epsilon = A \pm t^B + C(T - T_c) + D \quad (1)$$

where $t = (T - T_c)/T_c$; A , B , C and D are constants.

It may be noted that a similar expression for the variation of specific heat was predicted by the one-loop model.² Expression (1) describes the data very well for all the mixtures studied. Figure 5 below shows the data and the fit for a representative mixture, $x = 0.63$. For comparison, we reproduce here the x-ray data of $x = 0.642$ for which a similar fit has been done (Figure 6) by Jeong *et al.*⁵

Using the fit parameters we have plotted in Figure 7, the thermal variation of $\Delta\epsilon/\Delta T$ for three different mixtures, viz., $x = 0.55$, 0.63 and 0.72 . We observe firstly that the peaks resemble very closely the specific heat curves⁵ obtained near the critical point, and secondly that the height of the peak is much larger for $x = 0.63$ than for $x = 0.55$ or 0.72 . The peak heights obtained in this manner are

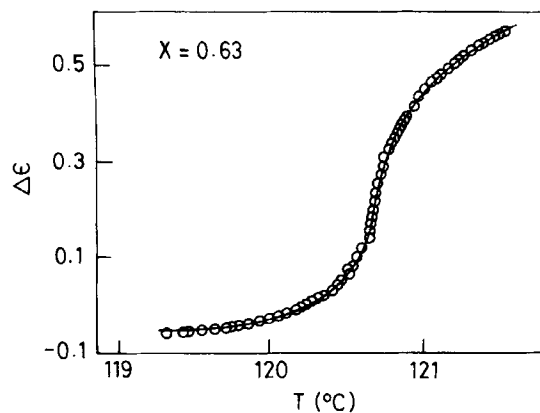


FIGURE 5 Plot showing the fitting of $\Delta\epsilon$ to Equation (1); circles are measured points and solid line the fitting.

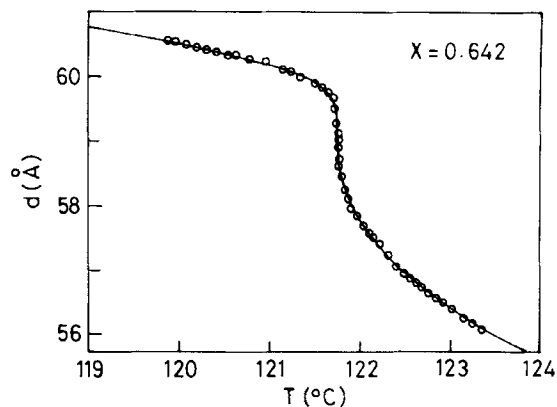


FIGURE 6 Fitting of the smectic layer spacing d to an expression similar to Equation 1 (from Reference 5).

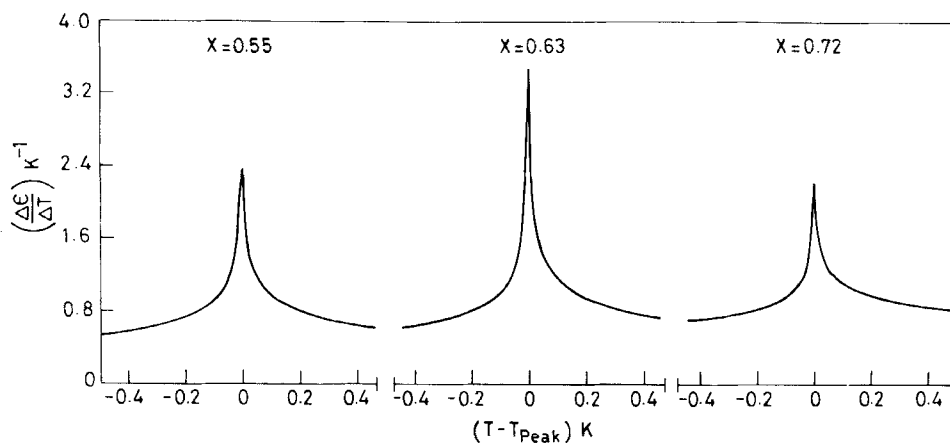


FIGURE 7 Plot of $\Delta\epsilon/\Delta T$ as a function of reduced temperature $T - T_{\text{peak}}$ for the three concentrations $x = 0.55, 0.63$ and 0.72 .

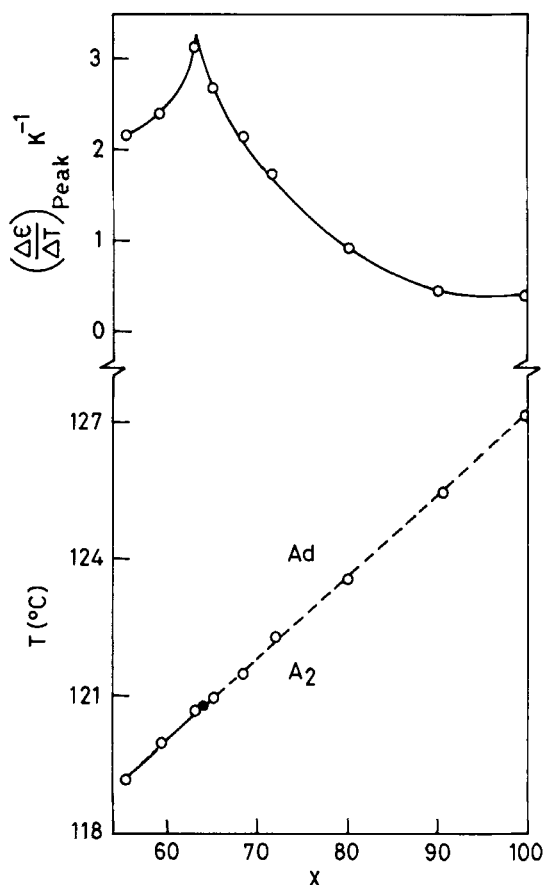
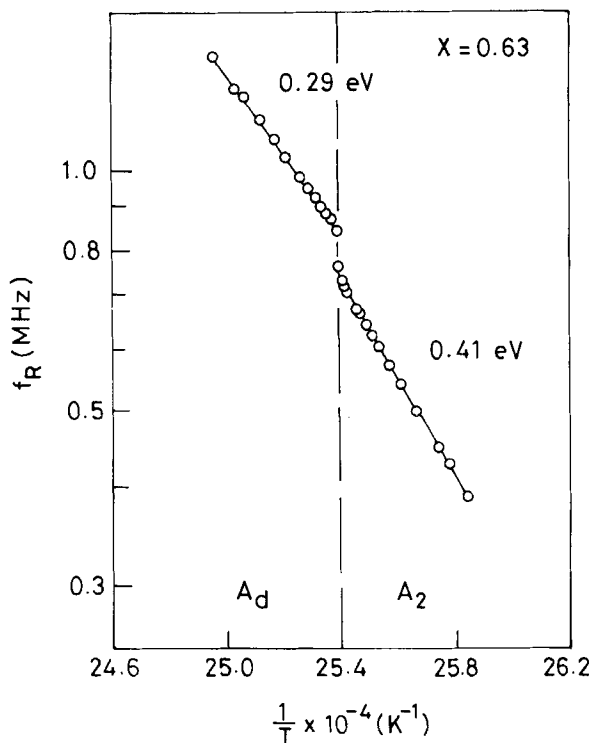


FIGURE 8 Top panel: Peak height of $\Delta\epsilon/\Delta T$ versus $T - T_{\text{peak}}$ curves plotted as a function of x . Bottom panel: Partial phase diagram of the binary system 110PCB0B + 90BCB. Solid line denotes the A_d - A_2 transition boundary while the dashed line represents the locus of "inflection points" in the supercritical region. The filled circle denotes the critical point estimated from peak height plots of $\Delta\epsilon/\Delta T$ curves.

plotted in Figure 8 as a function of x . It is seen that the peak height value increases from either side (lower as well as higher concentrations) on approaching the critical point concentration, which has been found to be $x = 0.64$, in excellent agreement with the value obtained from x-ray⁴ and calorimetric⁵ measurements.

DISPERSION STUDIES

The frequency of relaxation of ϵ_{\parallel} , f_R has been plotted (Figure 9) in the A_d and A_2 phases of the mixture $x = 0.63$. The results show that there is no drastic change in the f_R values between the A_d and A_2 phases. This probably explains the observation of a single relaxation even in the transition region contrary to the expected coexistence of two relaxations at a first-order transition. However, the activation

FIGURE 9 f_R versus $1/T$ plot for $x = 0.63$.

energies, W , in the A_d and A_2 phases, evaluated from the linear portions of the f_R versus $1/T$ plot are quite different; $W_{A_d} = 0.29\text{eV}$ and $W_{A_2} = 0.41\text{eV}$, i.e., $W_{A_2} > W_{A_d}$. Similar features were seen in an earlier study⁶ on a different material showing a A_d - A_2 transition.

In conclusion, we have carried out for the first time precise dielectric studies near the A_d - A_2 critical point. Data analysis has led to the identification of the critical point to be very near to $x = 0.64$ in excellent agreement with the values determined previously by x-ray and calorimetric methods. Measurements are in progress on another binary system which shows⁷ the A_d - A_2 critical point in the temperature-molecular length phase diagram. The results of these studies will be published separately.

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